16A, 35V - 150V Schottky Barrier Rectifier

FEATURES

TAIWAN

• AEC-Q101 qualified available

EMICONDUCTOR

- Low power loss, high efficiency
- Guard ring for overvoltage protection
- High surge current capability
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- DC to DC converters

MECHANICAL DATA

- Case: TO-220AC
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Mounting torque: 0.56 N·m maximum
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 1.86g (approximately)

KEY PARAMETERS				
PARAMETER	VALUE	UNIT		
I _F	16	А		
V _{RRM}	35 - 150	V		
I _{FSM}	150	А		
T _{J MAX}	150	°C		
Package	TO-220AC			
Configuration	Single die			



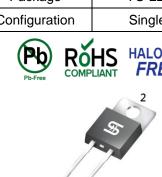




ABSOLUTE MAXIMUM RATIN				1		MDD	MDD	MDD	
PARAMETER	SYMBOL	MBR	MBR	MBR	MBR	MBR	MBR	MBR	UNIT
	••••••	1635	1645	1650	1660	1690	16100	16150	
Marking code on the device		MBR	MBR	MBR	MBR	MBR	MBR	MBR	
		1635	1645	1650	1660	1690	16100	16150	
Repetitive peak reverse voltage	V_{RRM}	35	45	50	60	90	100	150	V
Reverse voltage, total rms value	V _{R(RMS)}	24	31	35	42	63	70	105	V
Forward current	١ _F				16				А
Surge peak forward current									
8.3ms single half sine wave	I _{FSM}				150				Α
superimposed on rated load									
Peak repetitive forward current	I _{FRM}				32				А
(Rated V _R , Square Wave, 20KHz)	IFRM			1	02				~
Peak repetitive reverse surge current ⁽¹⁾	I _{RRM}		I			0.5			А
Voltage rate of change (Rated V_R)	dV/dt	10,000				V/µs			
Junction temperature	TJ	-55 to +150				°C			
Storage temperature	T _{STG}			-5	55 to +15	50			°C

Notes:

1. tp = 2.0µs, 1.0KHz





THERMAL PERFORMANCE			
PARAMETER	SYMBOL	ТҮР	UNIT
Junction-to-case resistance	R _{eJC}	3	°C/W

ELECTRICAL SPECIFICATIONS ($T_A = 25^{\circ}C$ unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	ТҮР	MAX	UNIT
Forward voltage ⁽¹⁾	MBR1635 MBR1645			-	0.63	V
	MBR1650 MBR1660			-	0.75	V
	MBR1690 MBR16100			-	0.85	V
	MBR16150		V	-	0.95	V
	MBR1635 MBR1645	- Ι _F = 16Α, Τ _J = 125°C	V _F	-	0.57	V
	MBR1650 MBR1660			-	0.65	V
	MBR1690 MBR16100			-	0.75	V
	MBR16150			-	0.92	V
Reverse current @ rated V _R ⁽²⁾	MBR1635 MBR1645 MBR1650 MBR1660	T _J = 25°C		-	500	μA
	MBR1690 MBR16100			-	300	μA
	MBR16150		1	-	100	μA
	MBR1635 MBR1645		I _R	-	15	mA
	MBR1650 MBR1660	T _J = 125°C		-	10	mA
	MBR1690 MBR16100			-	7.5	mA
	MBR16150			-	5	mA

Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms

ORDERING INFORMATION		
ORDERING CODE ⁽¹⁾⁽²⁾	PACKAGE	PACKING
MBR16x	TO-220AC	50 / Tube
MBR16xH	TO-220AC	50 / Tube

Notes:

1. "x" defines voltage from 35V(MBR1635) to 150V(MBR16150)

2. "H" means AEC-Q101 qualified



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

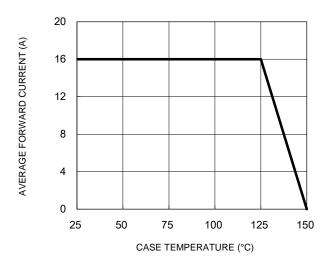
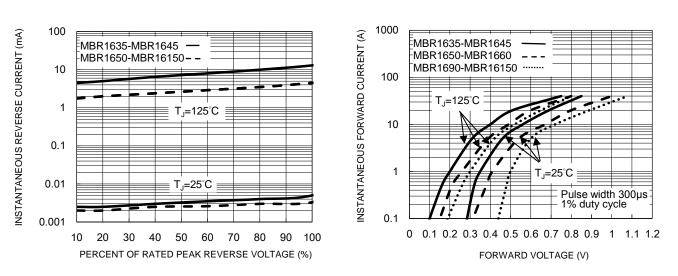


Fig.1 Forward Current Derating Curve

Fig.3 Typical Reverse Characteristics



1000

100

10

0.1

f=1.0MHz Vsig=50mVp-p

CAPACITANCE (pF)

Fig.5 Maximum Non-Repetitive Forward Surge Current

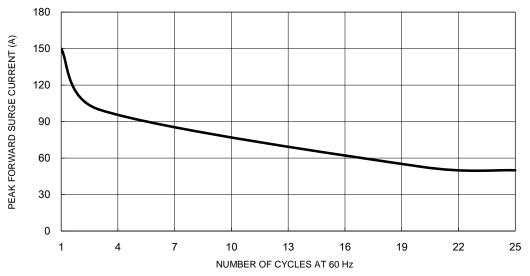


Fig.2 Typical Junction Capacitance

Fig.4 Typical Forward Characteristics

REVERSE VOLTAGE (V)

1

10

100



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

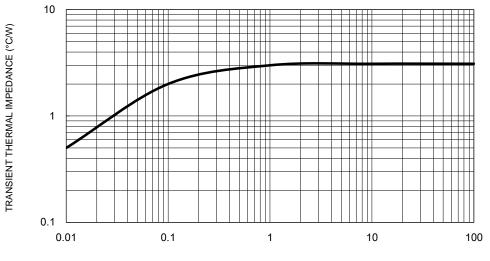
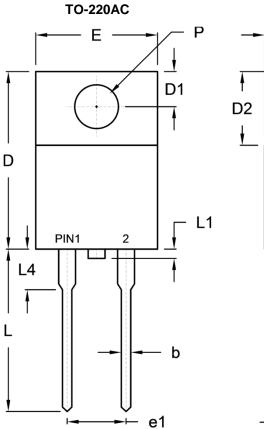


Fig.6 Typical Transient Thermal Impedance

PULSE DURATION (s)



PACKAGE OUTLINE DIMENSIONS



↑)2 ↓			c2
_	A2	c	

DIM.	Unit	Unit (mm)		(inch)	
	Min.	Max.	Min.	Max.	
A	4.42	4.76	0.174	0.187	
A2	2.20	2.80	0.087	0.110	
b	0.68	0.94	0.027	0.037	
с	0.35	0.64	0.014	0.025	
c2	1.14	1.40	0.045	0.055	
D	14.60	16.00	0.575	0.630	
D1	2.62	3.44	0.103	0.135	
D2	5.84	6.86	0.230	0.270	
Е	-	10.50	-	0.413	
e1	4.95	5.20	0.195	0.205	
L	13.19	14.79	0.519	0.582	
L1	0.00	1.60	0.000	0.063	
L4	2.80	4.20	0.110	0.165	
Р	3.54	4.00	0.139	0.157	

MARKING DIAGRAM



P/N	= Marking Code
G	= Green Compound
YWW	= Date Code
F	= Factory Code



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